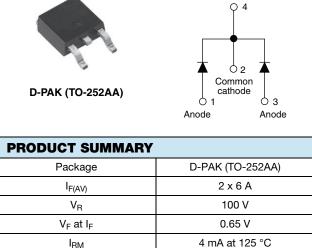


**Vishay Semiconductors** 

# Schottky Rectifier, 2 x 6 A



T<sub>.1</sub> max.

Diode variation

 $\mathsf{E}_{\mathsf{AS}}$ 

Revision: 03-Nov-10

Base common cathode

150 °C

Common cathode

6 mJ

## **FEATURES**

- · Low forward voltage drop
- Guard ring for enhanced ruggedness and long term reliability
- Halogen-free according to IEC 61249-2-21 definition
- Popular D-PAK outline
- Center tap configuration
- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Compliant to RoHS Directive 2002/95/EC

## DESCRIPTION

The VS-12CWQ10FN-M3 surface mount, center tap, Schottky rectifier series has been designed for applications requiring low forward drop and small foot prints on PC board. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I <sub>F(AV)</sub>	Rectangular waveform	12	A						
V <sub>RRM</sub>		100	V						
I <sub>FSM</sub>	t <sub>p</sub> = 5 μs sine	330	А						
V <sub>F</sub>	6 Apk, T <sub>J</sub> = 125 °C (per leg)	0.65	V						
TJ	Range	- 55 to 150	°C						

VOLTAGE RATINGS								
PARAMETER	SYMBOL	VS-12CWQ10FN-M3	UNITS					
Maximum DC reverse voltage	V <sub>R</sub>	100	V					
Maximum working peak reverse voltage	V <sub>RWM</sub>	100						

ABSOLUTE MAXIMUM RATINGS									
PARAMETER		SYMBOL	TEST CONDI	VALUES	UNITS				
Maximum average forward currentper legSee fig. 5per device			50 % duty cycle at T <sub>C</sub> = 135 °C	6	A				
		I <sub>F(AV)</sub>	$30 \times 10^{-100}$ Cycle at $1^{\circ}_{\circ} = 135^{\circ}_{\circ}$ C	12					
Maximum peak one cycle non-repetitive surge current per leg See fig. 7		I <sub>FSM</sub>	5 µs sine or 3 µs rect. pulse	Following any rated load condition and with	330	A			
			10 ms sine or 6 ms rect. pulse	rated $V_{RRM}$ applied	110				
Non-repetitive avalanche energy per leg		E <sub>AS</sub>	T <sub>J</sub> = 25 °C, I <sub>AS</sub> = 1 A, L = 12 mH		6	mJ			
Repetitive avalanche current per leg		I <sub>AR</sub>	Current decaying linearly to zero in 1 $\mu s$ Frequency limited by T_J maximum V_A = 1.5 x V_R typical		1	А			





**RoHS** COMPLIANT HALOGEN FREE

# VS-12CWQ10FN-M3

Vishay Semiconductors



ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST C	VALUES	UNITS				
		6 A	T 05 %C	0.80				
Maximum forward	V <sub>FM</sub> <sup>(1)</sup>	12 A	— T <sub>J</sub> = 25 °C	0.95	V			
voltage drop per leg See fig. 1		6 A	T 105 %C	0.65				
		12 A	— T <sub>J</sub> = 125 °C	0.78				
Maximum reverse leakage current per leg	I <sub>BM</sub> <sup>(1)</sup>	T <sub>J</sub> = 25 °C	$V_{\rm B}$ = Rated V <sub>B</sub>	1	mA			
See fig. 2	IRM W	T <sub>J</sub> = 125 °C	V <sub>R</sub> = naleu V <sub>R</sub>	4	IIIA			
Threshold voltage	V <sub>F(TO)</sub>				V			
Forward slope resistance	r <sub>t</sub>	$T_J = T_J$ maximum		20.68	mΩ			
Typical junction capacitance per leg	CT	$V_{R} = 5 V_{DC}$ , (test signal r	183	pF				
Typical series inductance per leg	L <sub>S</sub>	Measured lead to lead 5	5.0	nH				

## Note

 $^{(1)}\,$  Pulse width < 300  $\mu s,$  duty cycle < 2  $\,\%$ 

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range		$T_{J}$ <sup>(1)</sup> , $T_{Stg}$		- 55 to 150	°C				
Maximum thermal resistance,	per leg	Р	DC operation	3.0	°C/W				
junction to case	per device	R <sub>thJC</sub>	See fig. 4	1.5					
Approximate weight				0.3	g				
				0.01	oz.				
Marking device			Case style D-PAK (similar to TO-252AA)	12CWQ10FN					

## Note

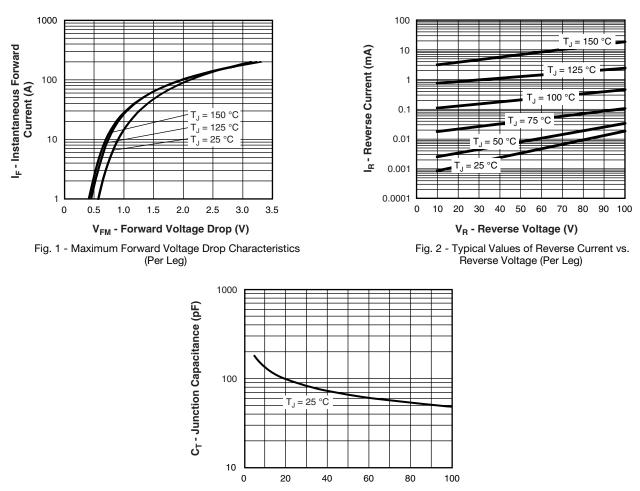
(1)  $\frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}}$  thermal runaway condition for a diode on its own heatsink



# VS-12CWQ10FN-M3

Schottky Rectifier, 2 x 6 A

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V<sub>R</sub> - Reverse Voltage (V)

Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage (Per Leg)

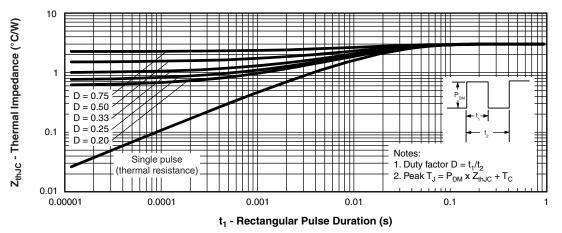


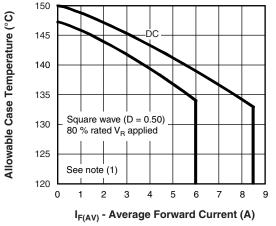
Fig. 4 - Maximum Thermal Impedance Z<sub>thJC</sub> Characteristics (Per Leg)

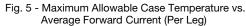
# **VS-12CWQ10FN-M3**

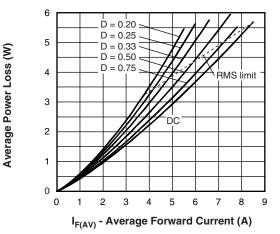
## **Vishay Semiconductors**

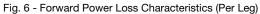
Schottky Rectifier, 2 x 6 A











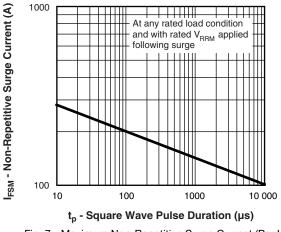


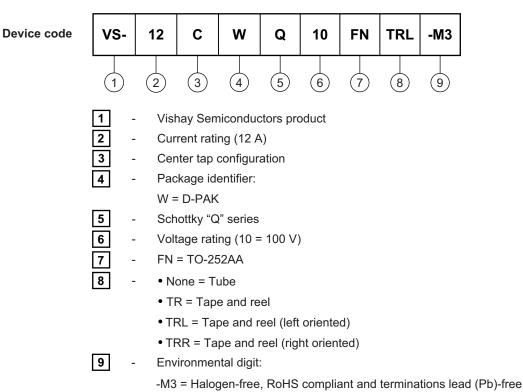
Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

### Note

- Formula used:  $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$ ; (1)
  - $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see fig. 6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$



## ORDERING INFORMATION TABLE



**ORDERING INFORMATION** (Example) **PREFERRED P/N QUANTITY PER T/R** MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION VS-12CWQ10FN-M3 75 3000 Antistatic plastic tube VS-12CWQ10FNTR-M3 2000 2000 13" diameter reel VS-12CWQ10FNTRL-M3 3000 3000 13" diameter reel VS-12CWQ10FNTRR-M3 3000 3000 13" diameter reel

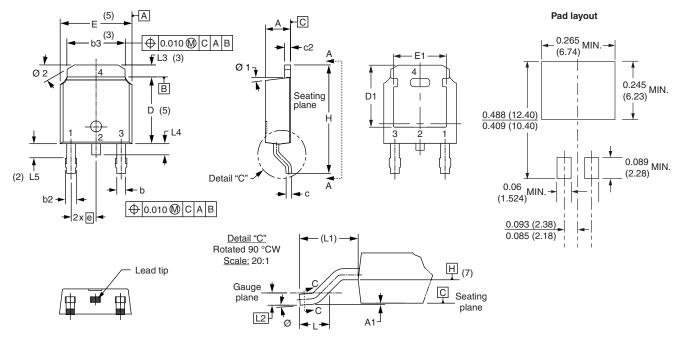
LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95016					
Part marking information	www.vishay.com/doc?95176					
Packaging information	www.vishay.com/doc?95033					
SPICE model	www.vishay.com/doc?95177					



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# D-PAK (TO-252AA)

## **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIN	IETERS	INCHES		IES NOTES		SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES	NOTES	STIVIDUL	MIN.	MAX.	MIN.	MAX.	NUTES
А	2.18	2.39	0.086	0.094			е	2.29	BSC	0.090	) BSC	
A1	-	0.13	-	0.005			Н	9.40	10.41	0.370	0.410	
b	0.64	0.89	0.025	0.035			L	1.40	1.78	0.055	0.070	
b2	0.76	1.14	0.030	0.045			L1	2.74	BSC	0.108	BREF.	
b3	4.95	5.46	0.195	0.215	3		L2	0.51	BSC	0.020	BSC	
с	0.46	0.61	0.018	0.024			L3	0.89	1.27	0.035	0.050	3
c2	0.46	0.89	0.018	0.035			L4	-	1.02	-	0.040	
D	5.97	6.22	0.235	0.245	5		L5	1.14	1.52	0.045	0.060	2
D1	5.21	-	0.205	-	3		Ø	0°	10°	0°	10°	
E	6.35	6.73	0.250	0.265	5		Ø1	0°	15°	0°	15°	
E1	4.32	-	0.170	-	3		Ø2	25°	35°	25°	35°	

#### Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Lead dimension uncontrolled in L5

<sup>(3)</sup> Dimension D1, E1, L3 and b3 establish a minimum mounting surface for thermal pad

<sup>(4)</sup> Section C - C dimension apply to the flat section of the lead between 0.13 and 0.25 mm (0.005 and 0.10") from the lead tip

(5) Dimension D, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

<sup>(6)</sup> Dimension b1 and c1 applied to base metal only

<sup>(7)</sup> Datum A and B to be determined at datum plane H

<sup>(8)</sup> Outline conforms to JEDEC outline TO-252AA

Document Number: 95016



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